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Eureka Microelectronics, Inc.

EK7309

PRELIMINARY Rev 0.2

DATA SHEET

256-Outputs Gate Driver

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TFT Gate Driver (256 Outputs)

1. GENERAL DESCRIPTION

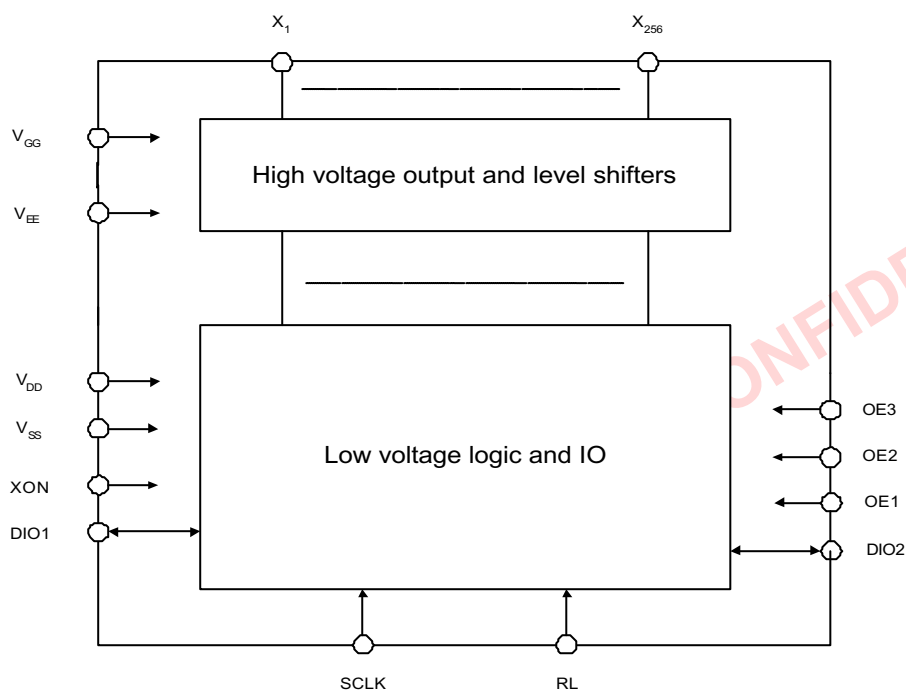
EK7309 is a TFT LCD gate driver with 256 outputs for XGA/SXGA display systems. The logic and control portion is implemented in standard CMOS circuits while the output drivers use high voltage CMOS design. The low voltage part includes a 256-stage bidirectional shift register with right and left shift I/O for cascading. The output of the shift register is then level translated to drive the high voltage output buffer. There are four supply voltages for EK7309. VDD/VSS are the supply voltages for logic interfaces. Typically VDD is at 3.3V while VSS is 0V. VGG and VEE are the supply voltages for the output driver. VEE is the most negative supply voltage for the internal substrate of EK7309.

EK7309 allows three output enable controls (OE1-3) and one global enable signal (XON).

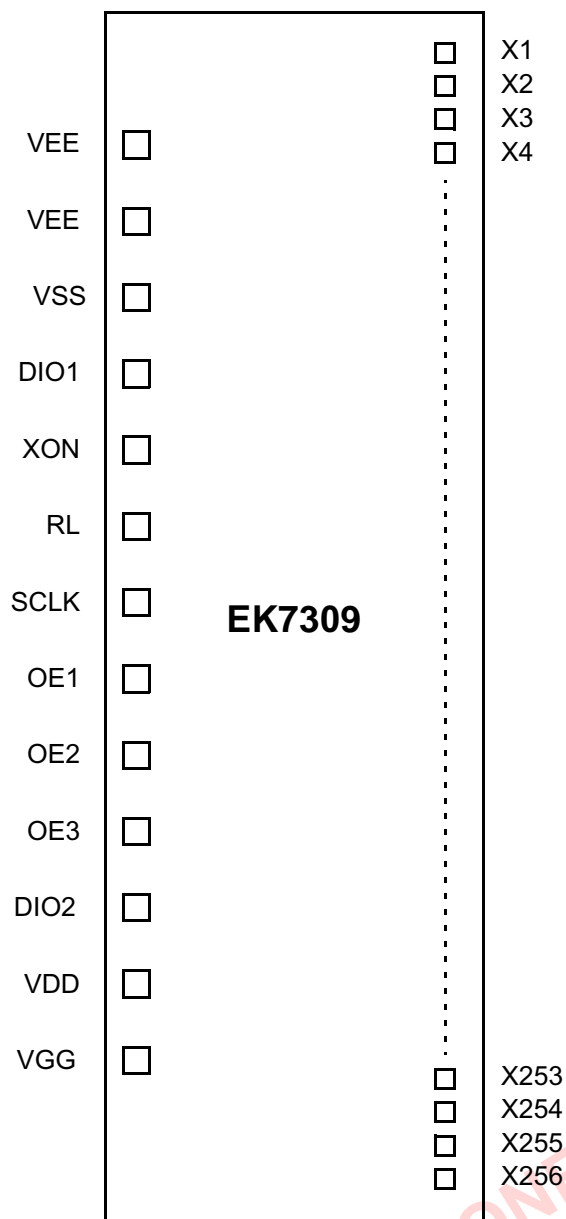
2. FEATURES

- 256 gate drive outputs
- Bidirectional shift control and cascading
- Output enable and global on control
- Maximum shift clock frequency up to 100KHz
- 3.3V CMOS logic I/O
- High voltage output drive
- Operating supply range
Logic (VDD-VSS: 3.3V)
Output Drive (VGG -VEE: 40V)
- TCP package

3. BLOCK DIAGRAM



4. PIN CONFIGURATION



IC top view. This diagram shows EK7309's pin configuration only. It does not necessarily correspond to the pad layout on the chip.

Figure-1

5. PIN FUNCTION DESCRIPTION

Name	Pin	Description									
SCLK	I	Shift clock. This is a 3.3V CMOS level input for shift register clock. The rising edge of SCLK is used.									
RL	I	Right/Left shift control. RL=1 is shift right (X1 -> X256), RL=0 is shift left (X256 -> X1).									
DIO1 DIO2	I/O	<table> <tr> <td></td><td>DIO1</td><td>DIO2</td></tr> <tr> <td>RL = "H"</td><td>Input</td><td>Output</td></tr> <tr> <td>RL = "L"</td><td>Output</td><td>Input</td></tr> </table>		DIO1	DIO2	RL = "H"	Input	Output	RL = "L"	Output	Input
	DIO1	DIO2									
RL = "H"	Input	Output									
RL = "L"	Output	Input									
OE1, OE2, OE3	I	Output enable control. The output is forced low when OE is high. OE1 controls output 1,4,...,253,256. The control is asynchronous to SCLK. OE2 controls output 2,5,...,251,254. The control is asynchronous to SCLK. OE3 controls output 3,6,...,252,255. The control is asynchronous to SCLK.									
XON	I	Global on control. When XON=0, all outputs are forced high. XON is asynchronous to SCLK.									
X [1-256]	O	Output drive. These are the gate drive outputs. The high level is VGG and the low level is VEE.									
VDD	P	Positive supply voltage for LV logic. This is typically 3.3V.									
VSS	P	Negative supply voltage for LV logic. This is typically 0V.									
VGG	P	Positive supply voltage for the output driver. This is typically the most positive supply voltage to EK7309.									
VEE	P	Negative supply voltage for the output drive and the substrate. This is the most negative supply voltage to EK7309.									

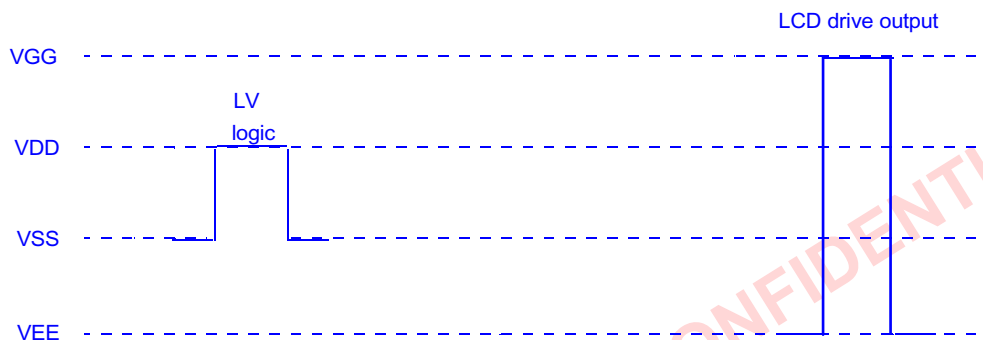


Figure-2

6. FUNCTIONAL DESCRIPTION

- 6.1 When RL is "HIGH" and a start pulse inputs the DIO1 pin, this pulse is shifted right by the shift control register at the rising edge of SCLK. While the output of the shift control register is "HIGH", the X_n [$n=1, 2, 3, \dots, 256$] is pulled to VGG. If the output of the shift control register is "LOW", X_n [$n=1, 2, 3, \dots, 256$] is pushed to VEE; DIO2 is pulled to high at the falling edge of the 256th clock of SCLK and is pushed to low at the falling edge of the 257th clock of SCLK. Please refer to operating waveform (1).
- 6.2 When RL is "LOW" and a start pulse inputs the DIO2 pin, this pulse is shifted left by the shift control register at the rising edge of SCLK. While the output of the shift control register is "HIGH", the X_n [$n=256, 255, 254, \dots, 1$] is pulled to VGG. If the output of the shift control register is "LOW", X_n [$n=256, 255, 254, \dots, 1$] is pushed to VEE; DIO1 is pulled to high at the falling edge of the 256th clock of SCLK and is pushed to low at the falling edge of the 257th clock of SCLK. Please refer to operating waveform (2).
- 6.3 OE1, OE2, and OE3 can disable X_n [$n=1, 2, 3, \dots, 256$]. They are asynchronous to SCLK.
 X_n [$n=1, 4, 7, \dots, 253, 256$] is pushed to VEE when OE1 is "HIGH".
 X_n [$n=2, 5, 8, \dots, 251, 254$] is pushed to VEE when OE2 is "HIGH".
 X_n [$n=3, 6, 9, \dots, 252, 255$] is pushed to VEE when OE3 is "HIGH".
Please refer to operating waveform (1) and (2).
- 6.4 The global on control XON can enable X_n [$n=1, 2, 3, \dots, 256$]. It is asynchronous to SCLK. Whenever XON is "LOW", all outputs of EK7309 are pulled to VGG at the same time. Please refer to operating waveform (3).

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7. TIMING DIAGRAM

RL=1, shift right

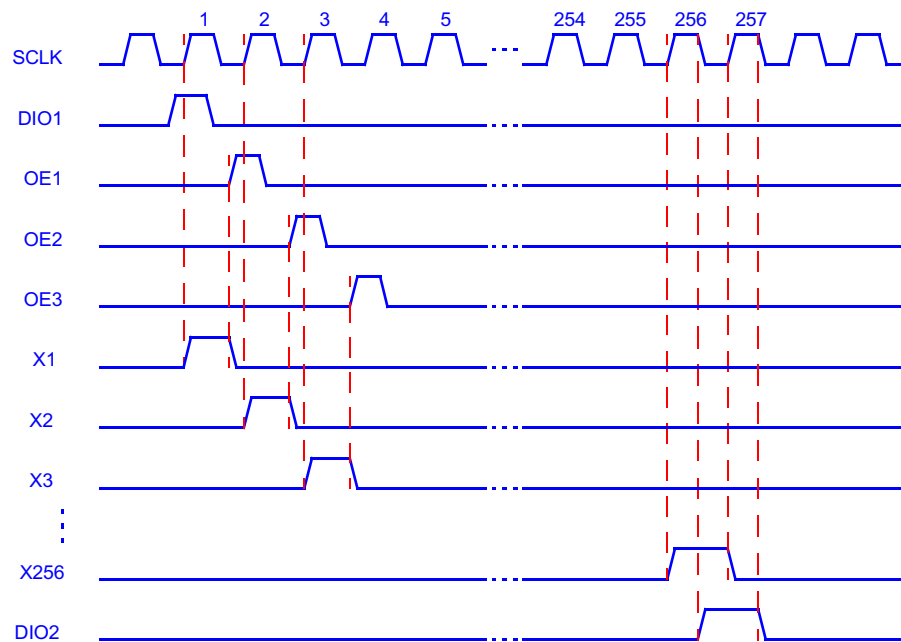


Figure-3 Operating Waveforms (1)

RL=0, shift left

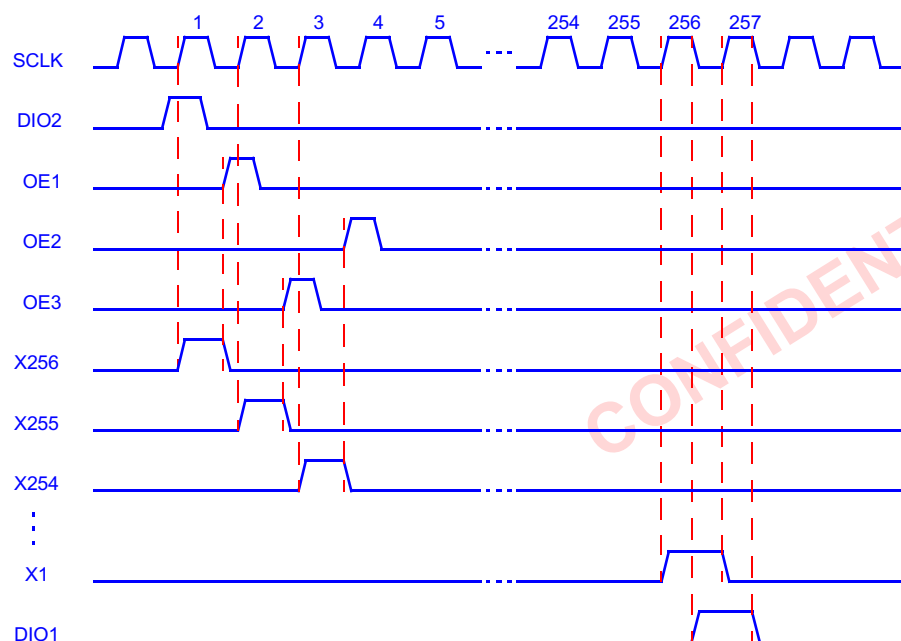


Figure-4 Operating Waveforms (2)

XON=0, RL=1

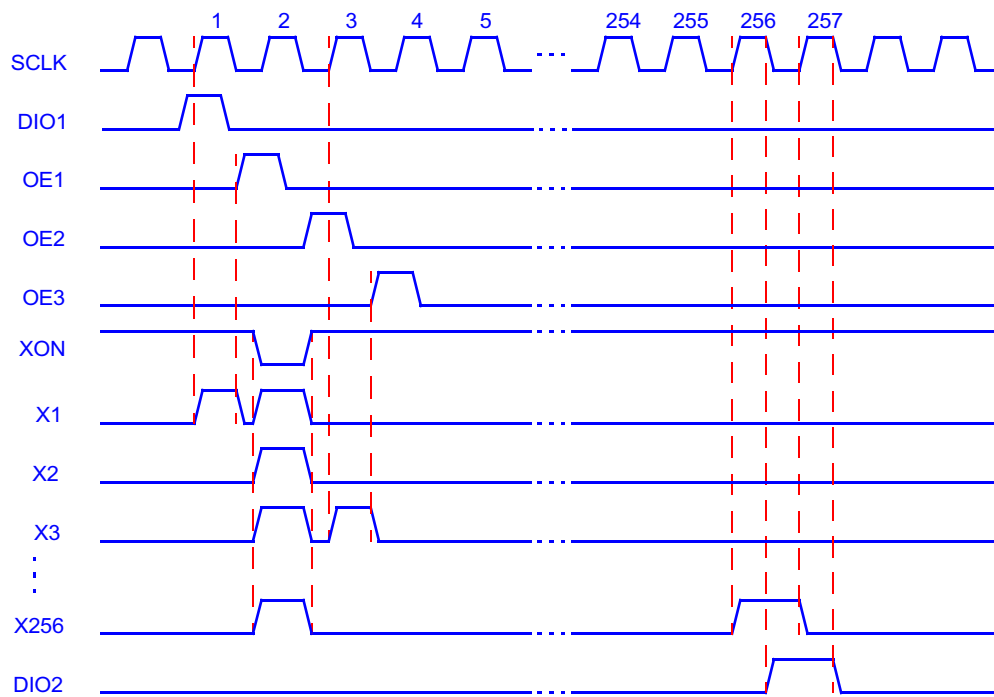


Figure-5 Operating Waveforms (3)

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8. ABSOLUTE MAXIMUM RATING

8.1 ABSOLUTE MAXIMUM RATING

$V_{LL} = 0V$

Symbol	Parameter	Rating	Unit
V_{DD}	Logic Supply Voltage	-0.3 ~ +7.0	V
V_{GG}	Positive Supply Voltage	-0.3 ~ +45	V
V_{EE}	Most Negative Supply Voltage	$V_{GG}-45 \sim +0.3$	V
V_{IN}	Logic Input Voltage	-0.3 ~ $V_{DD} + 0.3$	V
T_a	Operation Ambient Temperature	-30 ~ +85	°C
T_{stg}	Storage Temperature Range	-55 ~ +120	°C

8.2 RECOMMENDED OPERATING RANGE

$V_{LL} = 0V$

Symbol	Parameter	Min	Typ	Max	Unit
V_{DD}	Logic Supply Voltage	3.0	3.3	3.6	V
V_{GG}	Positive Supply Voltage	10		$V_{EE} + 40$	V
V_{EE}	Most Negative Supply Voltage	-25		-5	V
T_a	Operation Ambient Temperature	-20		+70	°C

Note: Power ON/OFF sequence is as below:

1. Power ON sequence: $V_{SS} \rightarrow V_{DD} \rightarrow V_{EE} \rightarrow V_{GG}$.
2. Power OFF sequence: $V_{GG} \rightarrow V_{EE} \rightarrow V_{DD} \rightarrow V_{SS}$.

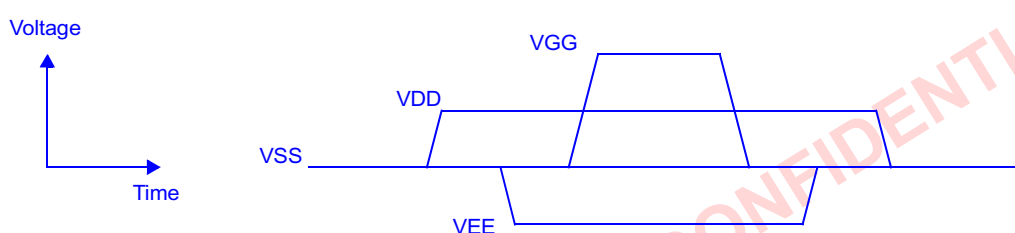


Figure-6

9. DC ELECTRICAL CHARACTERISTICS

9.1 Supply current

$T_a = 25^{\circ}\text{C}$, $V_{SS} = 0\text{V}$

Symbol	Parameter	Condition	Min	Typ	Max	Unit
I_{VDD1}	Operating current	$f_{SCLK} = 15.7\text{KHz}$ $f_{SL} = 60\text{Hz}$ $V_{DD} = 3.3\text{V}$ $V_{EE} = -15\text{V}$ $V_{GG} = 15\text{V}$ no loading			800	μA
I_{VGG1}					300	μA
I_{VDD}	Standby current	$V_{DD} = 3.3\text{V}$ $V_{EE} = -15\text{V}$ $V_{GG} = 15\text{V}$			600	μA
I_{VGG2}					100	μA

9.2 Input pin: RL, SCLK, OE1, OE2, OE3, XON

$T_a = 25^{\circ}\text{C}$, $V_{SS} = 0\text{V}$

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V_{IH1}	Input Voltage, HIGH		$0.8 \times V_{DD}$		V_{DD}	V
V_{IL1}	Input Voltage, LOW		0		$0.2 \times V_{DD}$	V
I_{LI1}	Input Leakage Current	XON except	-2		+2	μA

9.3 I/O pin: DIO1, DIO2

$T_a = 25^{\circ}\text{C}$, $V_{SS} = 0\text{V}$

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V_{IH2}	Input Voltage, HIGH		$0.8 \times V_{DD}$		V_{DD}	V
V_{IL2}	Input Voltage, LOW		0		$0.2 \times V_{DD}$	V
V_{OH}	Output Voltage, HIGH	$-100\mu\text{A}$	$V_{DD}-0.4$			V
V_{OL}	Output Voltage, LOW	$100\mu\text{A}$			0.4	V

9.4 Output pin: X1 ~ X256

$T_a = 25^{\circ}\text{C}$, $V_{SS} = 0\text{V}$

Symbol	Parameter	Condition	Min	Typ	Max	Unit
I_{LO1}	Output Leakage Current		-50		50	μA
RON-VGG		$V_{GG} = 15\text{V}$ $V_{EE} = -15\text{V}$ $V_{OM} = V_{GG} - 0.5\text{V}$ V_{OM} is X1-X256		600	1000	ohm
RON-VGG	Output ON Resistance	$V_{GG} = 15\text{V}$ $V_{EE} = -10\text{V}$ $V_{OM} = V_{EE} + 0.5\text{V}$ V_{OM} is X1-X256		600	1000	ohm

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10. AC CHARACTERISTICS $T_a = 25^{\circ}\text{C}$, $V_{SS} = 0\text{V}$

Symbol	Parameter	Condition	Min	Typ	Max	Unit
t_{SCLK}	Shift Clock Period		10			μs
t_{WH}	Shift Clock Pulse Width, HIGH		4			μs
t_{WL}	Shift Clock Pulse Width, LOW		4			μs
t_r	Shift Clock Rise Time				100	ns
t_f	Shift Clock Fall Time				100	ns
t_{su}	DIO1/DIO2 Input Setup Time		50			ns
t_n	DIO1/DIO2 Input Hold Time		350			ns
t_{pd1}	DIO1/DIO2 Output Delay Time	CL = 50pF			300	ns
t_{pd2}	Xn Output Delay Time	CL = 300pF			800	ns
t_{pd3}	Xn Output Delay Time (XON only)	CL = 300pF			1000	ns

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AC Characteristics Waveforms

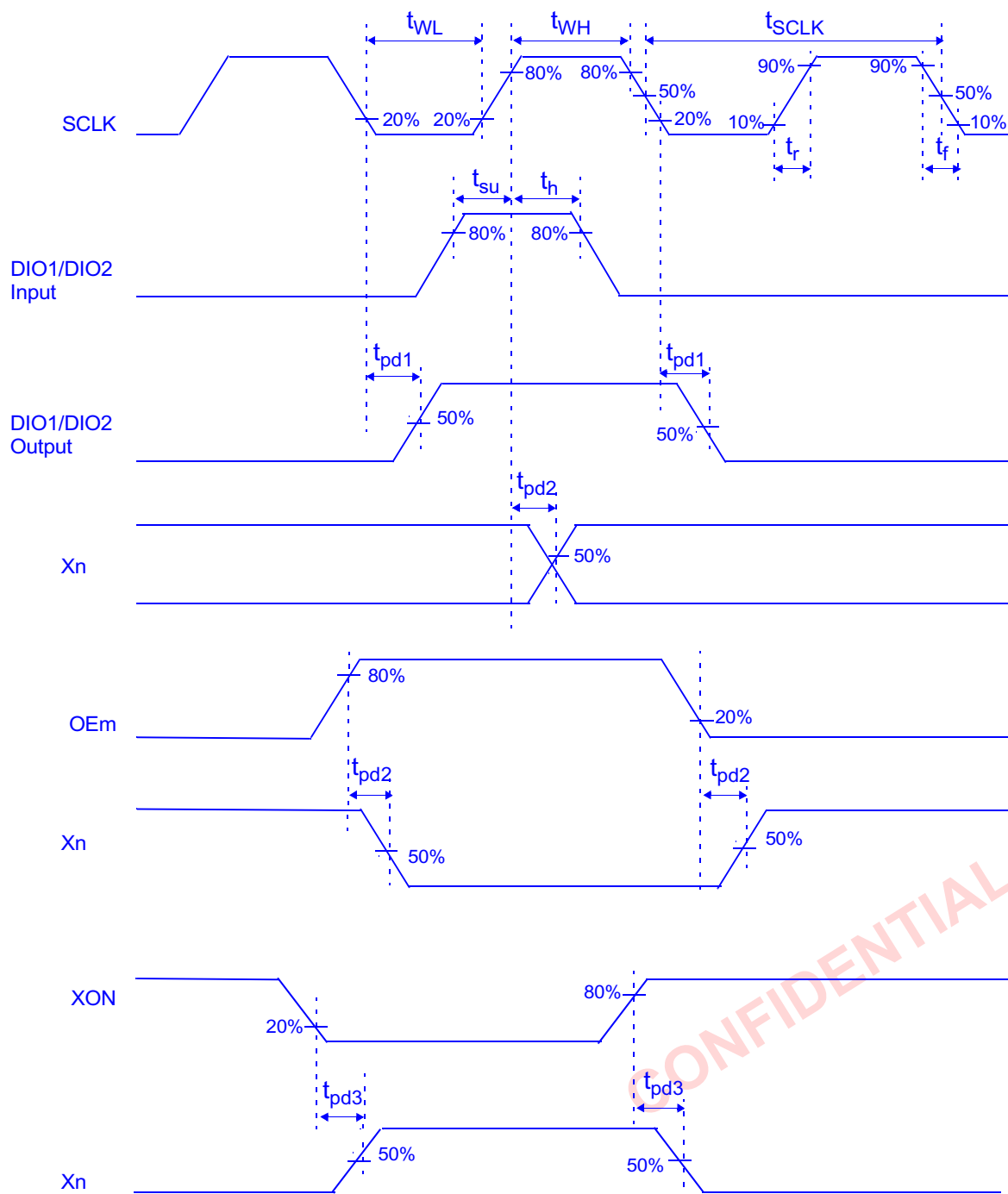


Figure-7

DEFINITIONS

Data Sheet status	
Objective specification	This data sheet contains target or goal specification for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specification.
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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